**Vishay High Power Products** 

### **Phase Control Thyristors** (Hockey PUK Version), 650 A

### **FEATURES**

- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)
- Lead (Pb)-free
- Designed and qualified for industrial level

#### **TYPICAL APPLICATIONS**

- · DC motor controls
- · Controlled DC power supplies
- · AC controllers

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
		650	А					
I <sub>T(AV)</sub>	T <sub>hs</sub>	55	°C					
		1290	А					
I <sub>T(RMS)</sub>	T <sub>hs</sub>	25	°C					
I <sub>TSM</sub>	50 Hz	8000	A					
	60 Hz	8380	~					
l <sup>2</sup> t	50 Hz	320	kA <sup>2</sup> s					
	60 Hz	292	KA-S					
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 2000	V					
tq	Typical	100	μs					
TJ		- 40 to 125	°C					

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE R	ATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT T <sub>J</sub> = T <sub>J</sub> MAXIMUM mA		
	04	400	500			
	08	800	900			
ST300CC	12	1200	1300	50		
0100000	16	1600	1700	50		
	18	1800	1800 1900			
	20	2000	2100			







TO-200AB (E-PUK)

PRODUCT SUMMARY	1
I <sub>T(AV)</sub>	650 A

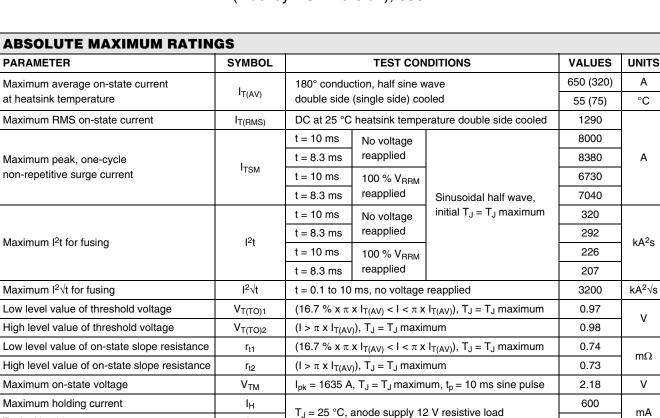
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RoHS

COMPLIANT

### Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 650 A



SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega,  t_r \leq$ 1 $\mu s$ $T_J$ = $T_J$ maximum, anode voltage $\leq$ 80 % $V_{DRM}$	1000	A/µs				
Typical delay time	t <sub>d</sub>	Gate current 1 A, dl <sub>g</sub> /dt = 1 A/ $\mu$ s V <sub>d</sub> = 0.67 % V <sub>DRM</sub> , T <sub>J</sub> = 25 °C	1.0					
Typical turn-off time	tq	$ \begin{array}{l} I_{TM}=300 \text{ A}, \ T_J=T_J \ maximum, \ dI/dt=40 \ A/\mu s, \\ V_R=50 \ V, \ dV/dt=20 \ V/\mu s, \ gate \ 0 \ V \ 100 \ \Omega, \ t_p=500 \ \mu s \end{array} $	100	μs				

 $I_{\rm L}$ 

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$	500	V/µs				
Maximum peak reverse and off-state leakage current	I <sub>RRM,</sub> I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	50	mA				

1000

Typical latching current



Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 650 A

TRIGGERING							
DADAMETED	OVMDOL				VALUES		
PARAMETER	SYMBOL	12	TEST CONDITIONS			UNITS	
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum,	$t_p \le 5 ms$	1(	0.0	w	
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	vv	
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \le 5 ms$	3	.0	А	
Maximum peak positive gate voltage	+ V <sub>GM</sub>		t < 5 mg	20		v	
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms			.0	v	
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Maximum required gate trigger/	200	-		
DC gate current required to trigger		$T_J = 25 \ ^{\circ}C$		100	200	mA	
		T <sub>J</sub> = 125 °C	current/voltage are the lowest	50	-		
		T <sub>J</sub> = - 40 °C	value which will trigger all units	2.5	-		
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C	12 V anode to cathode applied	1.8	3.0	V	
		T <sub>J</sub> = 125 °C		1.1	-		
DC gate current not to trigger	I <sub>GD</sub>		Maximum gate current/voltage not to trigger is the maximum	10.0		mA	
DC gate voltage not to trigger	$V_{GD}$	$T_J = T_J$ maximum	value which will not trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	0.25		v	

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum operating junction temperature range	TJ		- 40 to 125	O			
Maximum storage temperature range	T <sub>Stg</sub>		- 40 to 150				
Maximum thermal resistance, junction to heatsink	<b>B</b>	DC operation single side cooled	0.09	Э			
	R <sub>thJ-hs</sub>	DC operation double side cooled	0.04	K/W			
	Б	DC operation single side cooled	0.02				
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>	DC operation double side cooled	0.01				
Mounting force, ± 10 %			9800 (1000)	N (kg)			
Approximate weight			83	g			
Case style		See dimensions - link at the end of datasheet	TO-200AB (	E-PUK)			

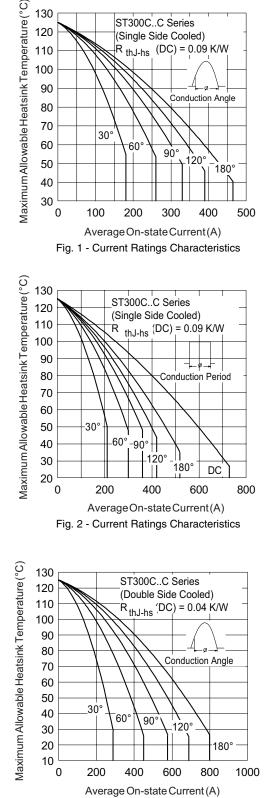
CONDUCTION ANGLE	SINUSOIDAL	SINUSOIDAL CONDUCTION		R CONDUCTION	TEST CONDITIONS	UNITS			
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS			
180°	0.010	0.011	0.007	0.007					
120°	0.012	0.012	0.012	0.013					
90°	0.015	0.015	0.016	0.017	$T_J = T_J maximum$	K/W			
60°	0.022	0.022	0.023	0.023					
30°	0.036	0.036	0.036	0.037					

Note

• The table above shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC

### Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 650 A







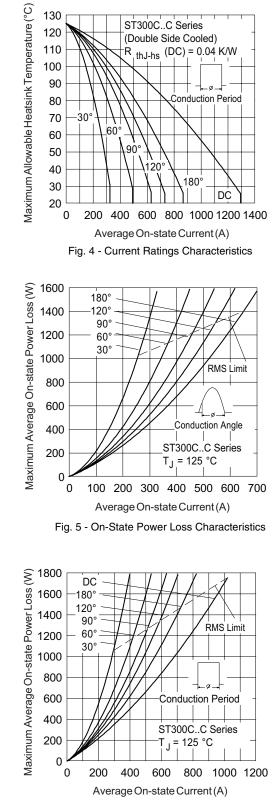
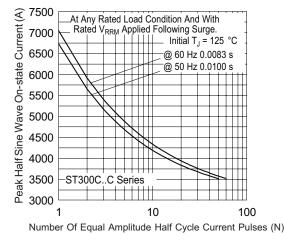


Fig. 6 - On-State Power Loss Characteristics

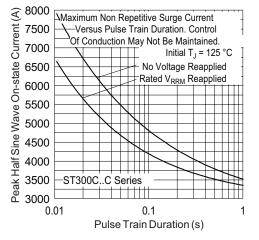


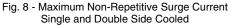
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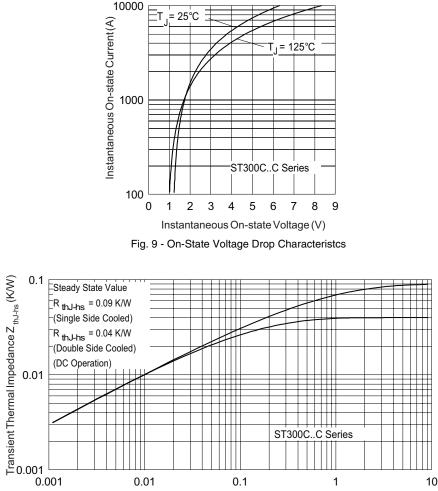
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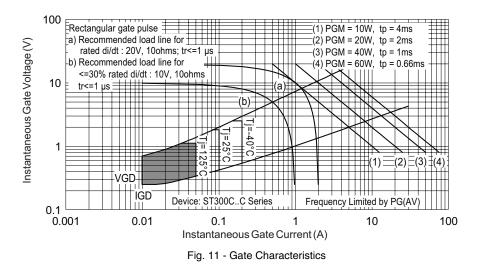
Square Wave Pulse Duration (s)

Fig. 10 - Thermal Impedance Z<sub>thJ-hs</sub> Characteristics

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#### Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 650 A



#### **ORDERING INFORMATION TABLE**

Device code	ST	30	0	с	20	С	1	-	PbF	
		2	3	4	5	6	7	8	9	I
	1 -		ristor							
	2 - 3 -			art numt						
	4 -		0 = Converter grade C = Ceramic PUK							
	5 -			de x 100	= V <sub>RRM</sub>	<sub>I</sub> (see V	oltage F	Ratings	table)	
	6 -	C =	PUK ca	ase TO-2	200AB (	E-PUK)				
	7 -	0 =	Eyelet t	erminals	s (gate a	and aux	iliary ca	thode u	insolder	ed leads)
		1 =	Fast-on	termina	ls (gate	and au	xiliary c	athode	unsolde	ered leads
		2 =	Eyelet t	erminals	s (gate a	and aux	iliary ca	thode s	oldered	leads)
		3 =	Fast-on	termina	ls (gate	and au	xiliary c	athode	soldere	d leads)
	8 -	Crit	ical dV/o	dt: • No	ne = 50	0 V/µs (	standar	d value	)	
				• L =	1000 V	∕/µs (sp	ecial se	lection)		
	9 -	Lea	d (Pb)-f	ree						

LINKS TO RELATED DOCUMENTS						
Dimensions http://www.vishay.com/doc?95075						
	•					

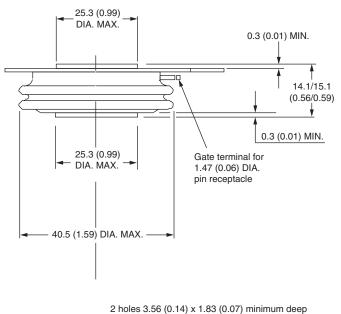


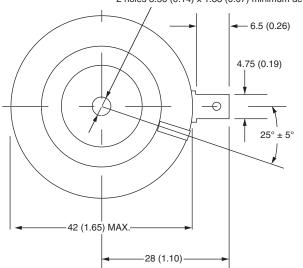
**Vishay Semiconductors** 

### TO-200AB (E-PUK)

#### **DIMENSIONS** in millimeters (inches)

Anode to gate Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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